

	<h2 style="color: orange;">JAN1N5806URS</h2>	
	Manufacturer Part Number:	JAN1N5806URS
	Manufacturer/Brand:	Microsemi
	Part of Description:	DIODE GEN PURP 150V 1A APKG
<p>Image may be representation. See specs for product details.</p>	Datasheets:	 JAN1N5806URS.pdf
	RoHs Status:	Contains lead / RoHS non-compliant
	Stock Condition:	New original, Stock Available.
	Ship From:	Hong Kong
	Shipment Way:	DHL/Fedex/TNT/UPS/EMS









Specifications

Part Number	JAN1N5806URS
Manufacturer	Microsemi
Description	DIODE GEN PURP 150V 1A APKG
Category	Discrete Semiconductor Products > Diodes - Rectifiers -
Part Status	Require For Quote & Check Stock
Voltage - Forward (Vf) (Max) @ If	875mV @ 1A
Voltage - DC Reverse (Vr) (Max)	150V
Supplier Device Package	A-MELF
Speed	Fast Recovery = 200mA (Io)
Series	Military, MIL-PRF-19500/477
Reverse Recovery Time (trr)	25ns
Packaging	Bulk
Package / Case	SQ-MELF, A
Operating Temperature - Junction	-65°C ~ 175°C
Mounting Type	Surface Mount
Diode Type	Standard
Current - Reverse Leakage @ Vr	1µA @ 150V
Current - Average Rectified (Io)	1A
Capacitance @ Vr, F	25pF @ 10V, 1MHz

JAN1N5806URS Electronic Components is 100% New Original from YIC Distributor, Search JAN1N5806URS Datasheets, PDF, Inventory at Y-IC.com Online, Order JAN1N5806URS Microsemi with Warrantied and Confidence. Ship by DHL/FedEx/TNT/UPS Express. Support Payment with Telegraphic Transfer(T/T) or PayPal.
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 <p>JAN1N5806 Microsemi Corporation DIODE GEN PURP 150V 2.5A AXIAL</p>	 <p>JAN1N5804US Microsemi Corporation DIODE GEN PURP 100V 2.5A D5A</p>	 <p>JAN1N5804 Microsemi Corporation DIODE GEN PURP 100V 2.5A AXIAL</p>	 <p>JAN1N5807 Microsemi Corporation DIODE GEN PURP 50V 6A AXIAL</p>

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JAN1N5806URS Electronic	JAN1N5806URS Components	JAN1N5806URS Distributor	JAN1N5806URS Image	JAN1N5806URS Part
JAN1N5806URS Price	JAN1N5806URS Manufacturer	JAN1N5806URS Picture	JAN1N5806URS Stock	JAN1N5806URS Inventory
JAN1N5806URS New	JAN1N5806URS Original	JAN1N5806URS Warranted	JAN1N5806URS RFQ	JAN1N5806URS Order Online